

- ★ Green Device Available
- ★ Super Low Gate Charge
- ★ Excellent Cdv/dt effect decline
- ★ Advanced high cell density Trench technology

Product Summary

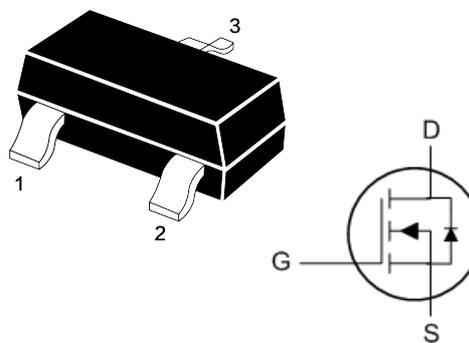


| BVDSS | RDSON | ID |
|-------|-------|------|
| 20V | 45 mΩ | 3.0A |

Description

SOT-23 Pin Configuration

The JH2302V is the high cell density trenched N-ch MOSFETs, which provides excellent RDSON and efficiency for most of the small power switching and load switch applications. The JH2302V meet the RoHS and Green Product requirement with full function reliability approved.



Absolute Maximum Ratings

| Symbol | Parameter | Rating | Units |
|----------------------------|--|------------|------------------|
| V_{DS} | Drain-Source Voltage | 20 | V |
| V_{GS} | Gate-Source Voltage | ± 12 | V |
| $I_D@T_A=25^\circ\text{C}$ | Continuous Drain Current, $V_{GS} @ 10V^1$ | 3.0 | A |
| $I_D@T_A=70^\circ\text{C}$ | Continuous Drain Current, $V_{GS} @ 10V^1$ | 1.2 | A |
| I_{DM} | Pulsed Drain Current ² | 12 | A |
| $P_D@T_A=25^\circ\text{C}$ | Total Power Dissipation ³ | 0.85 | W |
| T_{STG} | Storage Temperature Range | -55 to 150 | $^\circ\text{C}$ |
| T_J | Operating Junction Temperature Range | -55 to 150 | $^\circ\text{C}$ |

Thermal Data

| Symbol | Parameter | Typ. | Max. | Unit |
|-----------------|--|------|------|--------------------|
| $R_{\theta JA}$ | Thermal Resistance Junction-ambient ¹ | --- | 162 | $^\circ\text{C/W}$ |
| $R_{\theta JC}$ | Thermal Resistance Junction-Case ¹ | --- | --- | $^\circ\text{C/W}$ |

Electrical Characteristics (T_J=25°C unless otherwise specified)

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units |
|---|---|--|------|------|------|-------|
| Off Characteristic | | | | | | |
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _D =250μA | 20 | - | - | V |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =20V, V _{GS} =0V, | - | - | 1.0 | μA |
| I _{GSS} | Gate to Body Leakage Current | V _{DS} =0V, V _{GS} =±12V | - | - | ±100 | nA |
| On Characteristics | | | | | | |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} , I _D =250μA | 0.4 | 0.7 | 1.0 | V |
| R _{DS(on)} | Static Drain-Source on-Resistance <small>note2</small> | V _{GS} =4.5V, I _D =3A | - | 45 | 55 | mΩ |
| | | V _{GS} =2.5V, I _D =2A | - | 62 | 85 | |
| Dynamic Characteristics | | | | | | |
| C _{iss} | Input Capacitance | V _{DS} =10V, V _{GS} =0V, f=1.0MHz | - | 184 | - | pF |
| C _{oss} | Output Capacitance | | - | 38 | - | pF |
| C _{rss} | Reverse Transfer Capacitance | | - | 28 | - | pF |
| Q _g | Total Gate Charge | V _{DS} =10V, I _D =3A, V _{GS} =4.5V | - | 2.7 | - | nC |
| Q _{gs} | Gate-Source Charge | | - | 0.4 | - | nC |
| Q _{gd} | Gate-Drain("Miller") Charge | | - | 0.5 | - | nC |
| Switching Characteristics | | | | | | |
| t _{d(on)} | Turn-on Delay Time | V _{DS} =10V, I _D =3A, R _{GEN} =3Ω, V _{GS} =4.5V | - | 8 | - | ns |
| t _r | Turn-on Rise Time | | - | 27 | - | ns |
| t _{d(off)} | Turn-off Delay Time | | - | 26 | - | ns |
| t _f | Turn-off Fall Time | | - | 33 | - | ns |
| Drain-Source Diode Characteristics and Maximum Ratings | | | | | | |
| I _S | Maximum Continuous Drain to Source Diode Forward Current | | - | - | 3 | A |
| I _{SM} | Maximum Pulsed Drain to Source Diode Forward Current | | - | - | 12 | A |
| V _{SD} | Drain to Source Diode Forward Voltage | V _{GS} =0V, I _S =3A | - | - | 1.2 | V |

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

2. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%

Typical Performance Characteristics

Figure 1: Output Characteristics

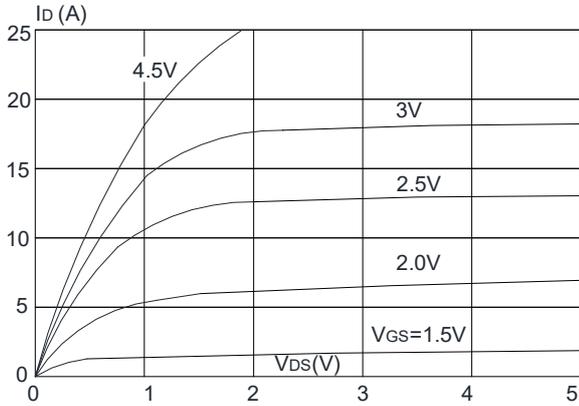


Figure 2: Typical Transfer Characteristics

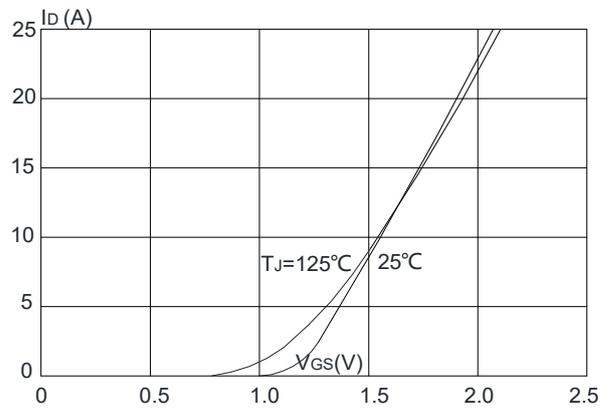


Figure 3: On-resistance vs. Drain Current

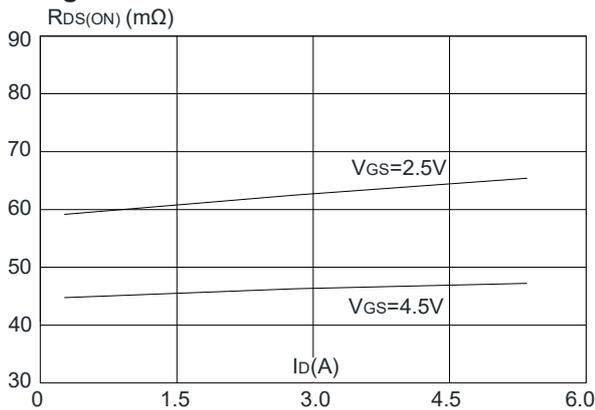


Figure 4: Body Diode Characteristics

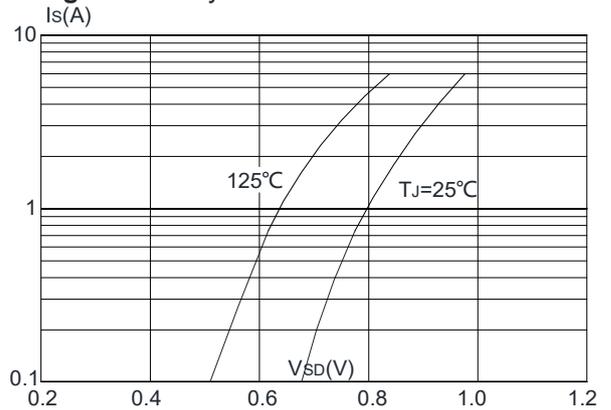


Figure 5: Gate Charge Characteristics

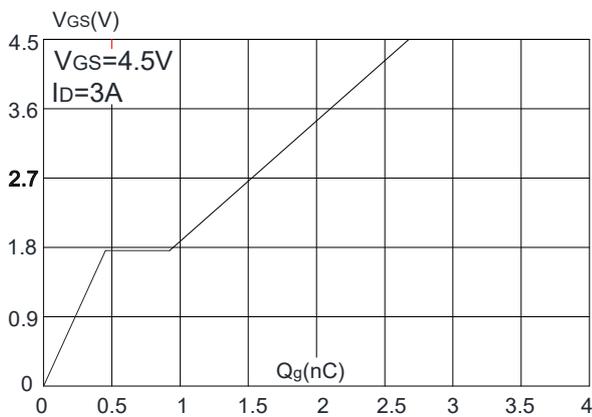


Figure 6: Capacitance Characteristics

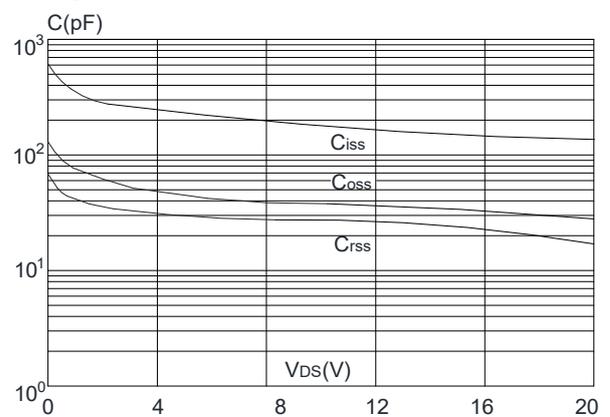


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

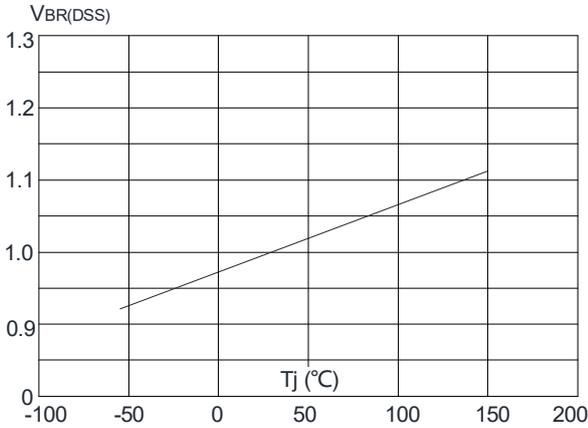


Figure 8: Normalized on Resistance vs. Junction Temperature

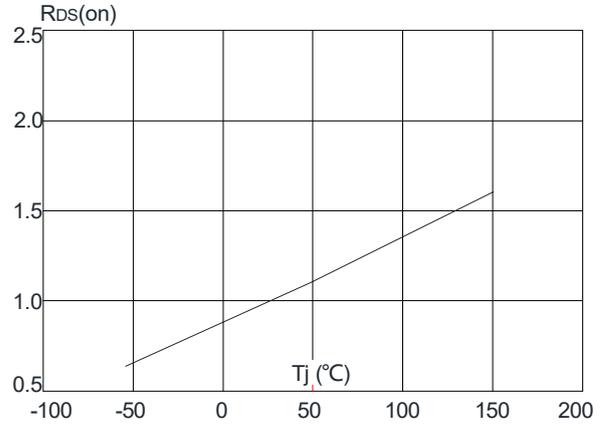


Figure 9: Maximum Safe Operating Area

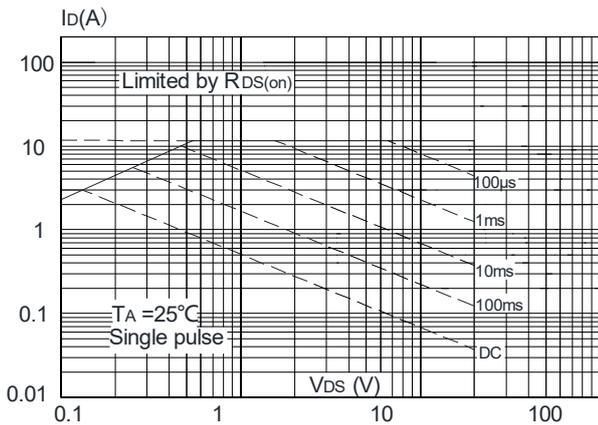


Figure 10: Maximum Continuous Drain Current vs. Ambient Temperature

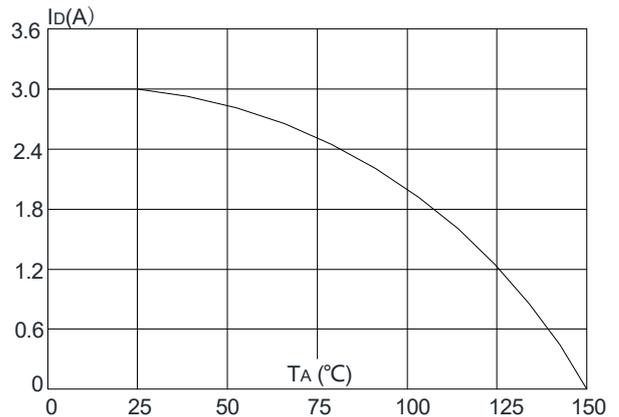
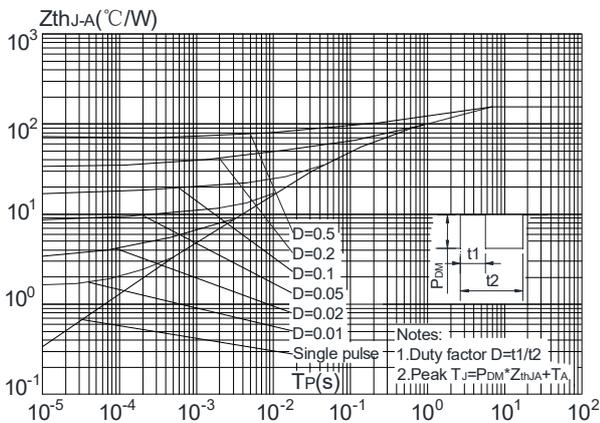
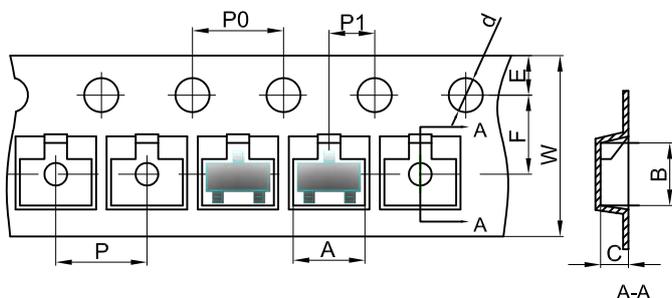


Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



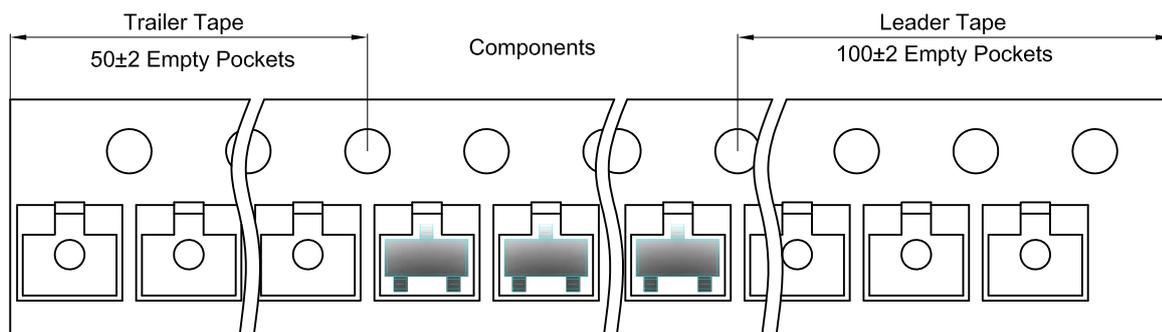
SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape

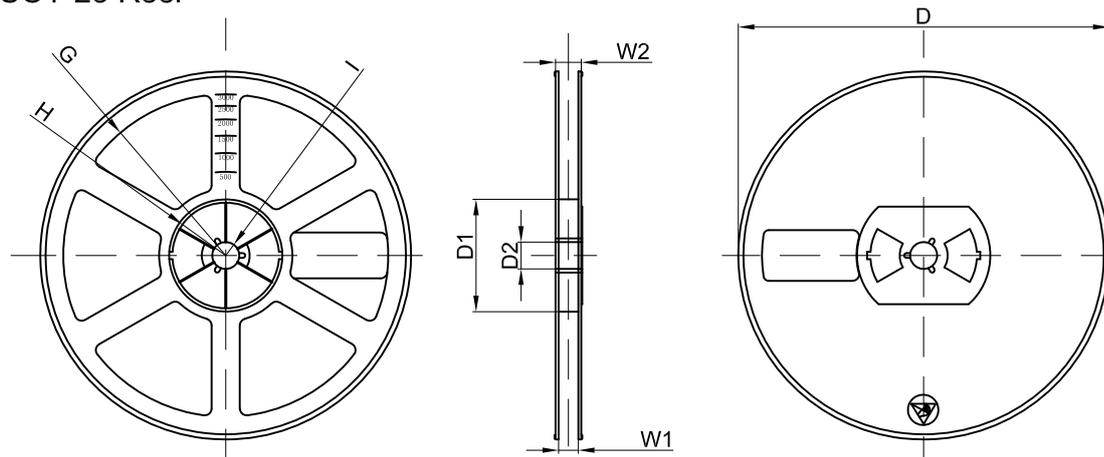


| Dimensions are in millimeter | | | | | | | | | | |
|------------------------------|------|------|------|-------|------|------|------|------|------|------|
| Pkg type | A | B | C | d | E | F | P0 | P | P1 | W |
| SOT-23 | 3.15 | 2.77 | 1.22 | Ø1.50 | 1.75 | 3.50 | 4.00 | 4.00 | 2.00 | 8.00 |

SOT-23 Tape Leader and Trailer

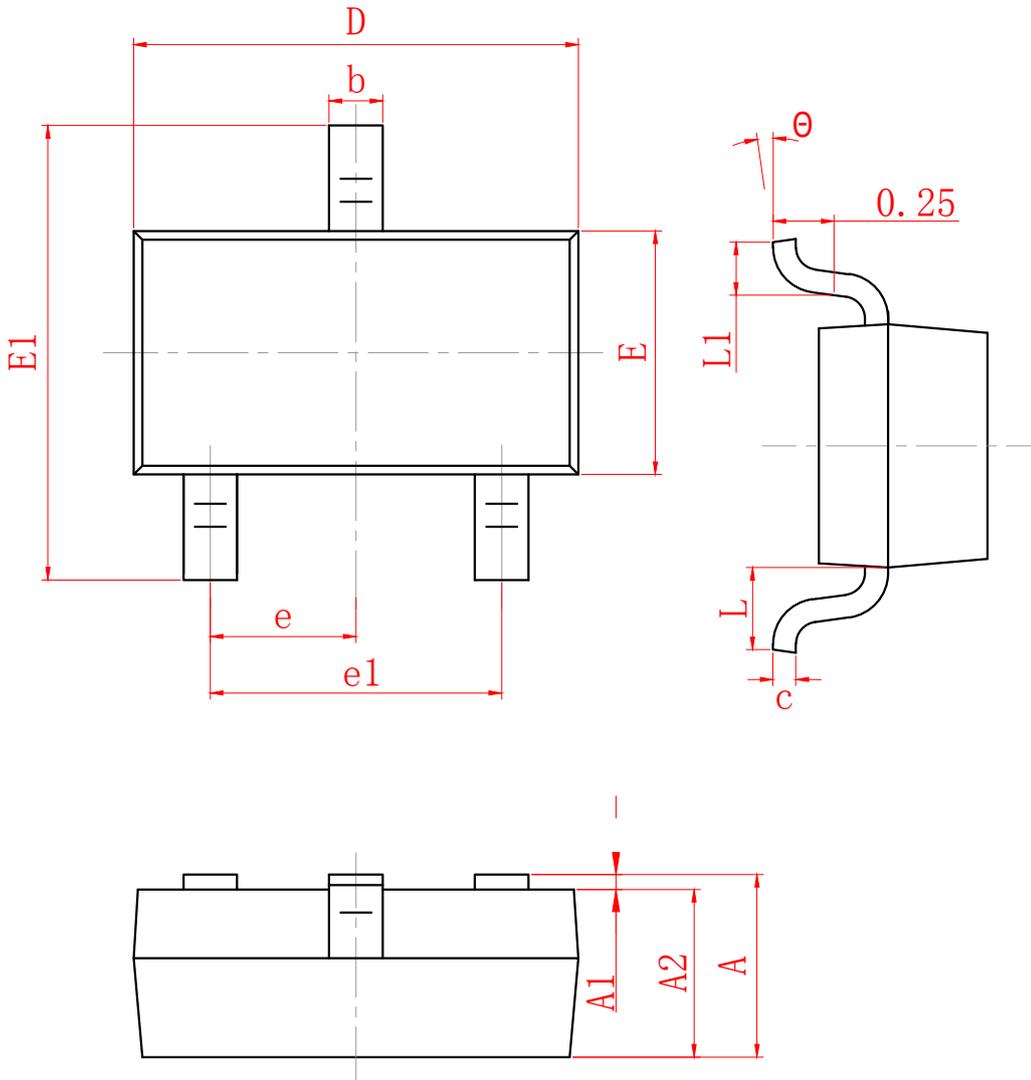


SOT-23 Reel



| Dimensions are in millimeter | | | | | | | | |
|------------------------------|---------|-------|-------|--------|--------|-------|------|-------|
| Reel Option | D | D1 | D2 | G | H | I | W1 | W2 |
| 7" Dia | Ø178.00 | 54.40 | 13.00 | R78.00 | R25.60 | R6.50 | 9.50 | 12.30 |

| REEL | Reel Size | Box | Box Size(mm) | Carton | Carton Size(mm) | G.W.(kg) |
|----------|-----------|------------|--------------|-------------|-----------------|----------|
| 3000 pcs | 7 inch | 45,000 pcs | 203×203×195 | 180,000 pcs | 438×438×220 | |



| SYMBOL | MILLIMETER | |
|----------|------------|-------|
| | MIN | MAX |
| A | 0.900 | 1.150 |
| A1 | 0.000 | 0.100 |
| A2 | 0.900 | 1.050 |
| b | 0.300 | 0.500 |
| c | 0.080 | 0.150 |
| D | 2.800 | 3.000 |
| E | 1.200 | 1.400 |
| E1 | 2.250 | 2.550 |
| e | 0.950 TYP | |
| e1 | 1.800 | 2.000 |
| L | 0.550 REF | |
| L1 | 0.300 | 0.500 |
| θ | 0° | 8° |

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